## Six-Channel Discrete-to-Digital Interface Sensing Open / Ground Signals

## DESCRIPTION

The HI-8420 is a six channel discrete-to-digital interface device. Mixed-signal CMOS technology is used to provide superior low-power performance. The HI-8420 has six separate Open / Ground sensing inputs. The device outputs are CMOS / TTL compatible and may be disabled (tri-state) using the $\overline{\mathrm{CE}}$ and $\overline{\mathrm{OE}}$ pins.

The device is a drop-in replacement for the DEI1026. For added functionality, the Holt HI-8422 offers eight channels of Open / Ground sensing and eight channels of 28 V / Ground sensing in a single device.

The HI-8420 is offered in a small footprint 16-pin plastic package. Please contact the Holt sales department for other packaging options.

## FEATURES

- Six independent Open / Ground sensing channels
- 5.0 V single supply operation
- Low power CMOS technology
- Military processing options available
- Drop in replacement for DEI1026


## FUNCTION TABLE

| Discrete <br> Input | $\overline{\mathrm{CE}}$ | $\overline{\mathrm{OE}}$ | Output |
| :---: | :---: | :---: | :---: |
| Open | 0 | 0 | 0 |
| Ground | 0 | 0 | 1 |
| X | 1 | X | High Z |
| X | X | 1 | High Z |

## PIN CONFIGURATION



16-Pin Plastic SOIC package (Narrow Body)

## BLOCK DIAGRAM



## PIN DESCRIPTIONS

| PIN | SYMBOL | FUNCTION |  |
| :---: | :---: | :---: | :--- |
| 1 | DESCRIPTION |  |  |
| 2 | IN1 | Discrete Input | Open / Ground sensing input, channel 1 |
| 3 | IN3 | Discrete Input | Open / Ground sensing input, channel 2 |
| 4 | IN4 | Discrete Input | Open / Ground sensing input, channel 3 |
| 5 | IN5 | Discrete Input | Open / Ground sensing input, channel 4 |
| 6 | IN6 | Discrete Input | Open / Ground sensing input, channel 5 input, channel 6 |
| 7 | $\overline{\text { OE }}$ | Digital input | Output Enable. OUT1-OUT6 are high-impedance if OE is high |
| 8 | $\overline{\text { CE }}$ | Digital input | Chip Enable. OUT1-OUT6 are high-impedance if CE is high |
| 9 | VDD | Power | Positive supply voltage 5.0 V |
| 10 | OUT6 | Tri-state output | Logic output, channel 6 |
| 11 | OUT5 | Tri-state output | Logic output, channel 5 |
| 12 | OUT4 | Tri-state output | Logic output, channel 4 |
| 13 | OUT3 | Tri-state output | Logic output, channel 3 |
| 14 | OUT2 | Tri-state output | Logic output, channel 2 |
| 15 | OUT1 | Tri-state output | Logic output, channel 1 |
| 16 | GND | Power | Ground |

## ABSOLUTE MAXIMUM RATINGS

| Supply voltage (VDD) | -0.3 V to +7 V |
| :--- | :---: |
| Logic input voltage range | -0.3 V to +5.5 V |
| Discrete input voltage range | -5 V to +35 V |
| Power dissipation at $25^{\circ} \mathrm{C}$ | 350 mW |
| Solder temperature | $275^{\circ} \mathrm{C}$ for 10 sec |
| Storage temperature | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

## RECOMMENDED OPERATING CONDITIONS

| Supply Voltage <br> VDD ............................... | 4.5 V to 5.5 V |  |
| :--- | :--- | :--- |
| Operating Temperature Range |  |  |
| Industrial Screening | $\ldots . . . . .$. | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Hi-Temp Screening | ...... | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |

NOTE: Stresses above absolute maximum ratings or outside recommended operating conditions may cause permanent damage to the device. These are stress ratings only. Operation at the limits is not recommended.

## ELECTRICAL CHARACTERISTICS

$\mathrm{VDD}=5.0 \mathrm{~V} \pm 10 \%, \mathrm{GND}=\mathrm{OV}, \mathrm{TA}=$ Operating Temperature Range (unless otherwise specified).

| PARAMETER | SYMBOL | CONDITION | MIN | TYP | MAX | UNITS |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DISCRETE INPUTS | VsG | Input voltage to give high output |  |  | 3.0 | V |
| Ground state input voltage | Vso | Input voltage to give low output | 3.5 |  |  | V |
| Open state input voltage | RIG | Resistor from input to ground <br> to give high output | 0 |  | 100 | $\Omega$ |
| Ground state input resistor | RIO | Resistor from input to ground <br> to give low output | 100 |  |  | $\mathrm{~K} \Omega$ |
| Open state input resistor | IIO | Current sourced into $100 \Omega$ <br> to ground | -100 | -330 |  | $\mathrm{\mu A}$ |
| Input source current | IIR | VIN $=35 \mathrm{~V}, \mathrm{VDD}=0 \mathrm{~V}$ |  |  | 5.0 | mA |
| Reverse leakage current |  |  |  |  |  |  |

## ELECTRICAL CHARACTERISTICS (Cont.)

$\mathrm{VDD}=5.0 \mathrm{~V} \pm 10 \%, G N D=0 \mathrm{~V}, \mathrm{TA}_{\mathrm{A}}=$ Operating Temperature Range (unless otherwise specified).

| PARAMETER | SYMBOL | CONDITION | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| LOGIC INPUTS ( $\overline{\mathrm{CE}, \overline{\mathrm{OE}})}$ |  |  |  |  |  |  |
| Input Voltage Input voltage HI <br> Input voltage LO | $\begin{aligned} & \hline \mathrm{V}_{\mathrm{IH}} \\ & \mathrm{~V}_{\mathrm{IL}} \end{aligned}$ |  | 2.0 |  | 0.8 | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| Input currentInput sink <br> Input source | $\begin{aligned} & \hline \mathrm{IH} \\ & \mathrm{ILL} \end{aligned}$ | $\begin{aligned} & \mathrm{VIH}=\mathrm{VDD} \\ & \mathrm{VIL}=0 \mathrm{~V} \end{aligned}$ | -1.0 |  | 1.0 | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ |
| OUTPUTS |  |  |  |  |  |  |
| $\begin{array}{lr}\text { Logic output voltage } & \text { High } \\ \text { Low }\end{array}$ | $\overline{\mathrm{VOH}}$ Vol | $\begin{aligned} \hline \mathrm{IOH} & =-5 \mathrm{~mA} \\ \mathrm{IOL} & =5 \mathrm{~mA} \end{aligned}$ | 2.4 |  | 0.4 | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |
| $\begin{array}{lr}\text { Logic output voltage (CMOS) } & \text { High } \\ \text { Low }\end{array}$ | Vor <br> VoL | $\begin{aligned} & \text { IOH }=-100 \mathrm{uA} \\ & \mathrm{IOL}=100 \mathrm{uA} \end{aligned}$ | VDD - 0.2 |  | 0.2 |  |
| Tri-state output current | loz | Vout $=0 \mathrm{~V}$ or VDD |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| SUPPLY CURRENT |  |  |  |  |  |  |
| VDD current | IDD | VIN = VdD (all inputs) |  | 5 | 10 | mA |
| SWITCHING CHARACTERISTICS |  |  |  |  |  |  |
| Propagation delay IN to OUT | tLL, thL |  |  |  | 150 | ns |
| Output enable time | tzL, tzH | From $\overline{\mathrm{CE}}$ or $\overline{\mathrm{OE}}$ |  |  | 25 | ns |
| Output disable time | tız, thz | From $\overline{\mathrm{CE}}$ or $\overline{\mathrm{OE}}$ |  |  | 25 | ns |

## TIMING DIAGRAMS



## ORDERING INFORMATION

| PART <br> NUMBER | PACKAGE <br> DESCRIPTION | TEMPERATURE <br> RANGE | PROCESS <br> FLOW | BURN <br> IN | LEAD <br> FINISH |
| :--- | :---: | :---: | :---: | :---: | :---: |
| HI-8420PSI | 16 PIN PLASTIC SOIC (NARROW BODY) | $-40^{\circ} \mathrm{C} \mathrm{TO}+85^{\circ} \mathrm{C}$ | I | NO | SOLDER |
| HI-8420PST | 16 PIN PLASTIC SOIC (NARROW BODY) | $-55^{\circ} \mathrm{C} \mathrm{TO}+125^{\circ} \mathrm{C}$ | T | NO | SOLDER |

## 16-PIN PLASTIC SMALL OUTLINE (SOIC) - NB

(Narrow Body)


